# **UC Berkeley**

# **UC Berkeley Previously Published Works**

# **Title**

Patterning-Induced Ferromagnetism of Fe3GeTe2 van der Waals Materials beyond Room Temperature

# **Permalink**

https://escholarship.org/uc/item/7qn5d6jw

# Journal

Nano Letters, 18(9)

# **ISSN**

1530-6984

### **Authors**

Li, Qian Yang, Mengmeng Gong, Cheng <u>et al.</u>

### **Publication Date**

2018-09-12

# DOI

10.1021/acs.nanolett.8b02806

Peer reviewed

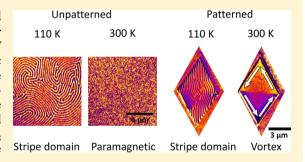
# Patterning-Induced Ferromagnetism of Fe<sub>3</sub>GeTe<sub>2</sub> van der Waals **Materials beyond Room Temperature**

Qian Li,<sup>†</sup> Mengmeng Yang,<sup>†</sup> Cheng Gong,<sup>‡</sup> Rajesh V. Chopdekar,<sup>§</sup> Alpha T. N'Diaye,<sup>§</sup> John Turner, I Gong Chen, Andreas Scholl, Padraic Shafer, Elke Arenholz, Andreas K. Schmid, Sheng Wang, Kai Liu, Nan Gao, Alemayehu S. Admasu, Sang-Wook Cheong, Chanyong Hwang, Isa Li, Alemayehu S. Admasu, Sang-Wook Cheong, Chanyong Hwang, Cheng Wang, Chanyong Hwang, Cheng Wang, Cheng Feng Wang,<sup>†</sup> Xiang Zhang,<sup>‡®</sup> and Ziqiang Qiu\*,<sup>†®</sup>

Supporting Information

Downloaded via UNIV OF CALIFORNIA BERKELEY on April 14, 2020 at 21:58:49 (UTC). See https://pubs.acs.org/sharingguidelines for options on how to legitimately share published articles.

ABSTRACT: Magnetic van der Waals (vdW) materials have emerged as promising candidates for spintronics applications, especially after the recent discovery of intrinsic ferromagnetism in monolayer vdW materials. There has been a critical need for tunable ferromagnetic vdW materials beyond room temperature. Here, we report a real-space imaging study of itinerant ferromagnet Fe<sub>3</sub>GeTe<sub>2</sub> and the enhancement of its Curie temperature well above ambient temperature. We find that the magnetic long-range order in Fe<sub>3</sub>GeTe<sub>2</sub> is characterized by an unconventional out-of-plane stripe-domain phase. In Fe<sub>3</sub>GeTe<sub>2</sub> microstructures patterned by a focused ion beam, the out-of-plane stripe domain phase undergoes a surprising transition at 230 K to an



in-plane vortex phase that persists beyond room temperature. The discovery of tunable ferromagnetism in Fe<sub>3</sub>GeTe<sub>2</sub> materials opens up vast opportunities for utilizing vdW magnets in room-temperature spintronics devices.

KEYWORDS: Magnetic van der Waals material, stripe-domain phase, vortex phase, spin-reorientation transition, room-temperature ferromagnetism

he recent discovery of magnetic long-range order in twodimensional (2D) van der Waals (vdW) materials<sup>1,2</sup> opens up unprecedented opportunities for fundamental physics and device applications. The ability to control spin orientations of 2D magnets at room temperature will be at the core of nextgeneration spintronic logic and memory devices. Despite the great progress made via various synthesis methods such as exfoliation<sup>1,2</sup> and epitaxial growth,<sup>3,4</sup> a great challenge remains in achieving tunable ferromagnetism in vdW materials at ambient temperatures, especially in terms of controlling the spin orientation, magnetic domain phase, and the magnetic long-range order. Here, we report an unambiguous observation of a tunable ferromagnetic domain phase in patterned Fe<sub>3</sub>GeTe<sub>2</sub> microstructures with an enhanced Curie temperature above room temperature. Fe<sub>3</sub>GeTe<sub>2</sub> is an itinerant ferromagnet that has a high Curie temperature ( $T_{\rm C} \approx 230~{\rm K}$ ) and stability among bulk magnetic vdW materials. 5-7 Consisting of two-dimensional (2D) atomic planes bonded weakly by vdW attraction, the magnetic structure of Fe<sub>3</sub>GeTe<sub>2</sub> can be regarded as stacked 2D Heisenberg ferromagnetic sheets that are stacked and magnetically coupled along the caxis of the crystal.8 Bulk magnetometry and localized X-ray spectroscopy both show that the spins within each sheet are ferromagnetically aligned with a perpendicular magnetic anisotropy that favors an out-of-plane (c-axis) magnetization.

Received: July 10, 2018 Revised: August 7, 2018 Published: August 16, 2018

<sup>&</sup>lt;sup>†</sup>Department of Physics, University of California, Berkeley, California 94720, United States

 $<sup>^{\</sup>ddagger}$ Nano-Scale Science and Engineering Center (NSEC), University of California, 3112 Etcheverry Hall, Berkeley, California 94720, United States

<sup>§</sup>Advanced Light Source and <sup>∥</sup>NCEM, Molecular Foundry, Lawrence Berkeley National Laboratory, Berkeley, California 94720, United States

<sup>&</sup>lt;sup>1</sup>Department of Physics, University of California, Davis, California 95616, United States

Department of Physics, Georgetown University, Washington, D.C. 20057, United States

 $<sup>^{</sup>abla}$ Rutgers Center for Emergent Materials and Department of Physics and Astronomy, Rutgers, The State University of New Jersey, Piscataway, New Jersey 08854, United States

<sup>&</sup>lt;sup>O</sup>Korea Research Institute of Standards and Science, Yuseong, Daejeon 305-340, Republic of Korea

<sup>◆</sup>International Center for Quantum Materials, School of Physics, Peking University, Beijing 100871, China

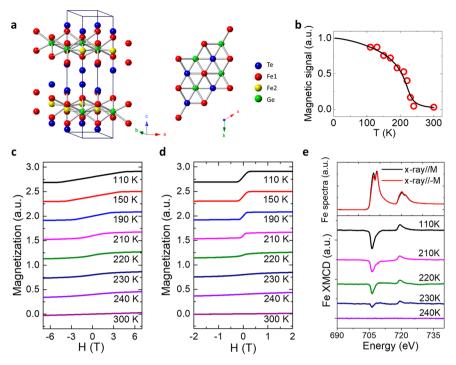


Figure 1. Crystal structure and magnetic measurement of Fe<sub>3</sub>GeTe<sub>2</sub>. (a) Crystal structure (side view and top view) of Fe<sub>3</sub>GeTe<sub>2</sub>. (b) Temperature dependence of the bulk Fe<sub>3</sub>GeTe<sub>2</sub> magnetization (black line) measured using SQUID in a 0.7 T magnetic field along the magnetization easy axis (c axis) after zero-field cooling. The red circles represent the Fe XMCD signal. Magnetic hysteresis loops measured with SQUID in magnetic fields applied (c) perpendicular to and (d) parallel to the c axis of bulk Fe<sub>3</sub>GeTe<sub>2</sub> crystal at different temperatures. (e) Fe 2p level X-ray absorption spectra (XAS) at T = 110 K for magnetization parallel (black line) and antiparallel (red line) to the incident X-rays. The difference of the XAS (XMCD signal) measures the Fe<sub>3</sub>GeTe<sub>2</sub> magnetic long-range order. Both SQUID and XMCD data show  $T_C \approx 230$  K for bulk Fe<sub>3</sub>GeTe<sub>2</sub>.

The coupling between adjacent sheets seems to depend sensitively on temperature, chemical composition, lattice parameters, etc., 9,10 leading to a complex magnetic behavior that is readily tuned by its environment. For example, the perpendicular magnetic anisotropy depends sensitively on the chemical environment and tensile strain. <sup>11</sup> Fe<sub>3</sub>GeTe<sub>2</sub> surfaces exhibit a range of magnetic domain patterns (e.g., wavy-stripe-, spike-like-, and bubble-like patterns) caused by different mechanisms such as domain branching near the sample surface, 12 a possible transition from ferromagnetic to antiferromagnetic interlayer coupling, <sup>13</sup> magnetic tip-induced domain structures, <sup>14</sup> etc. Anomalous Hall effect <sup>15,16</sup> and Kondo effect<sup>17</sup> measurements suggest a similar behavior of Fe<sub>3</sub>GeTe<sub>2</sub> to ferromagnetic ultrathin films, making it a promising candidate for spintronic applications. Given that vdW materials consist of weakly bonded 2D layers and that magnetic anisotropy could establish magnetic long-range order in a 2D Heisenberg system, 18,19 all experimental results on Fe<sub>3</sub>GeTe<sub>2</sub> suggest the likelihood that anisotropy is the primary driving force for stabilizing magnetic long-range order in 2D Fe<sub>3</sub>GeTe<sub>2</sub> atomic planes. In other words, other than the different values for  $T_{\rm C}$  due to the dimensionality effect and the sensitive dependence of the magnetic behavior on interlayer coupling, the magnetic properties of bulk Fe<sub>3</sub>GeTe<sub>2</sub> resemble largely those of a 2D Fe<sub>3</sub>GeTe<sub>2</sub> atomic plane. In this Letter, we report a magnetic microscopy study of Fe<sub>3</sub>GeTe<sub>2</sub> and demonstrate the tunability of the spin orientation and the  $T_{\rm C}$ of Fe<sub>3</sub>GeTe<sub>2</sub> in patterned microstructures.

Bulk Fe<sub>3</sub>GeTe<sub>2</sub> consists of weakly bonded Fe<sub>3</sub>Ge layers that alternate with two Te layers (Figure 1a). The Fe atoms occupy two inequivalent Wyckoff sites denoted as Fe1 and Fe2: Fe1 atoms form a hexagonal net, and Fe2 atoms are bonded

covalently with Ge atoms to form a hexagonal structure of P6<sub>3</sub>/ mmc space group. Because of the weak vdW bonding, Fe<sub>3</sub>GeTe<sub>2</sub> flakes peeled from a bulk crystal have the flake surface parallel to the Fe<sub>3</sub>Ge layers. Macroscopic hysteresis loops of a Fe<sub>3</sub>GeTe<sub>2</sub> crystal were measured using superconducting quantum interference device (SQUID) magnetometry with magnetic fields applied along both out-of-plane (field parallel to c axis) and in-plane directions (Figure 1c,d). We observed a saturation field of ~0.26 T for out-of-plane hysteresis loops and a saturation field of ~5.0 T for in-plane hysteresis loops at 110 K, indicating an out-of-plane magnetic easy axis. It is interesting to note the absence of magnetic remanence in the easy-axis hysteresis loop that also appears in many other magnetic vdW materials (discussed later). Temperature dependence of the magnetization was obtained with a 0.7 T magnetic field applied along the out-of-plane magnetic easy axis (Figure 1b). The magnetization decreases with increasing temperature and vanishes at ~230 K, showing a ferromagnetic to paramagnetic-phase transition at  $T_{\rm C} \approx 230~{\rm K}$ for a bulk Fe<sub>3</sub>GeTe<sub>2</sub> crystal. X-ray absorption spectra (XAS) were taken at the Fe 2p level using circularly polarized X-rays at normal incidence to the c-facet of a Fe<sub>3</sub>GeTe<sub>2</sub> crystal, and Xray magnetic circular dichroism (XMCD) was obtained by calculating the difference of XAS for magnetization parallel and antiparallel to the X-ray incidence direction (Figure 1e). The nonzero XMCD clearly shows the ferromagnetic order of the Fe moment in Fe<sub>3</sub>GeTe<sub>2</sub> at T < 230 K. These XMCD measurements were performed using a total electron yield mode that probes about 10 nm depth from the top surface.<sup>20</sup> We find that the temperature dependence of the XMCD signal follows exactly the temperature dependence of the magnetization measured by SQUID, indicating the homogeneity of

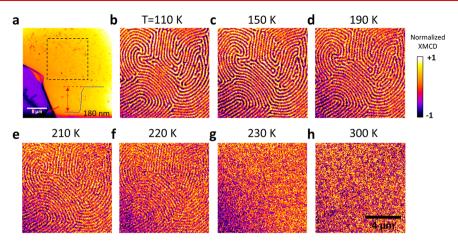


Figure 2. Temperature-dependent domain imaging of  $Fe_3GeTe_2$ . (a) PEEM topography image of a  $Fe_3GeTe_2$  flake (golden color) on a silicon substrate (purple color). The lower-right inset shows line scan obtained with an atomic force microscope along the red line from which the  $Fe_3GeTe_2$  flake thickness of 180 nm is determined. The dashed box  $(10 \, \mu m x 10 \, \mu m)$  indicates the area from which magnetic domains were imaged. (b-h) Magnetic-stripe domains of  $Fe_3GeTe_2$  at different temperatures. Disappearance of the stripe domains above 230 K confirms the Curie temperature of 230 K. Scale bar and color bar are for magnetic-domain images.

the sample along the c axis so that the XMCD measurement can be used to represent the bulk magnetic properties of  $Fe_3GeTe_2$ .

The lack of magnetic remanence along the easy magnetization axis is a characteristic feature of Fe<sub>3</sub>GeTe<sub>2</sub> and many other magnetic vdW materials, suggesting a domain phase of the magnetic long-range order. That is, the strong dipolar energy, along with a strong perpendicular magnetic anisotropy preference for out-of-plane magnetization in Fe<sub>3</sub>GeTe<sub>2</sub>, forces the formation of up- and down-magnetized domains. To explore the Fe<sub>3</sub>GeTe<sub>2</sub> magnetic domain phase, magnetic domains of the as-made sample were imaged using photoemission electron microscopy (PEEM) at the Fe  $L_3$  edge (706.3 eV). Figure 2 shows the magnetic domain images from a 180 nm thick Fe<sub>3</sub>GeTe<sub>2</sub> flake. The film exhibits stripe (or labyrinth) domains below 230 K, with the bright and dark stripes having equal width ( $\sim$ 140 nm on average in each type). Note that the domain contrast remains unchanged for a variety of in-plane stripe orientations; therefore, we identify the stripes as magnetic domains having up- and down-magnetization perpendicular to the sample surface. Above 230 K, the stripe domains disappear. XAS measurements above 230 K show zero XMCD signal so that the absence of the stripe domains indicates a paramagnetic state rather than a magnetic singledomain state. The PEEM result is consistent with the macroscopic magnetometry in that Fe<sub>3</sub>GeTe<sub>2</sub> has a perpendicular magnetization with  $T_{\rm C} \approx 230$  K. The equal width of up and down stripes also explains the zero magnetic remanence of the easy-axis hysteresis loop (Figure 1), which measures the spatially averaged magnetization. Another study has suggested a possible transition from ferromagnetic to antiferromagnetic interlayer coupling at ~150 K.13 No abrupt changes to the stripe domains (domain contrast, shape, width, or orientation) were observed in our sample near  $\sim 150 \text{ K}^{13}$ .

The formation of the stripe domains in Fe<sub>3</sub>GeTe<sub>2</sub> indicates the dominant role of dipolar interaction over exchange interaction and magnetic anisotropy in Fe<sub>3</sub>GeTe<sub>2</sub>.<sup>21</sup> In fact, the stripe-domain phase in Figure 2 strongly resembles the stripe-domain phase in perpendicularly magnetized magnetic thin films<sup>22–24</sup> and coupled multilayers.<sup>25,26</sup> By assuming ferromagnetic coupling along the *c* axis between 2D magnetic

sheets of  $Fe_3GeTe_2$ , the flakes can be treated as a single sheet (after scaling the interaction parameters)<sup>1,2</sup> or equivalently as a perpendicularly magnetized thin film that is described by the following Hamiltonian:<sup>27</sup>

$$\begin{split} H &= \frac{J}{2} \int [\nabla \cdot \vec{n}(\vec{x})]^2 d^2 \vec{x} - K \int n_z^2(\vec{x}) d^2 \vec{x} \\ &- \frac{\Omega}{4} \int \frac{[\vec{n}(\vec{x}) - \vec{n}(\vec{x}')]^2 - 3\{\vec{\nu} \cdot [\vec{n}(\vec{x}) - \vec{n}(\vec{x}')]\}}{|\vec{x} - \vec{x}'|^3} d^2 \vec{x} d^2 \vec{x}' \end{split}$$

where  $\vec{n}(\vec{x})$  is the unit vector of the magnetization at position  $\vec{x}$ on a 2D plane, J is the Heisenberg exchange interaction, K is the overall magnetic anisotropy (which includes both the perpendicular magneto crystalline anisotropy and the shortrange part of dipolar interaction),  $\Omega = \mu^2/a^3$  is the dipolar interaction strength ( $\mu$  is the magnetic moment per spin, and ais the lattice constant), and  $\vec{v} = (\vec{x} - \vec{x}')/|\vec{x} - \vec{x}'|$  is the unit vector from  $\vec{x}$  to  $\vec{x}$  on the 2D plane. It is well-known and reflected in the Hamiltonian that magnetic long-range order does not exist in the absence of K and  $\Omega^{18}$  but could be stabilized by a nonzero anisotropy, 19 which is believed to be responsible for the ferromagnetic order in 2D atomic layer of Cr<sub>2</sub>Ge<sub>2</sub>Te<sub>6</sub><sup>1</sup> and CrI<sub>3</sub><sup>2</sup>. In the limit where the dipolar interaction dominates the magnetic anisotropy, the dipolar interaction  $\Omega$  should stabilize a magnetic-stripe domain phase with a stripe width of  $\sim J/\Omega$ (on the order of 10<sup>2</sup> nm for most ferromagnetic materials). <sup>27,28</sup> As the magnetic anisotropy increases to gradually dominate the dipolar interaction, the stripe width (L) increases exponentially,<sup>24</sup> eventually exceeding the sample size, leading to the socalled anisotropy-stabilized single-domain phase. This phenomenon actually reflects a cross-over behavior of the 2D Heisenberg system by changing the characteristic length scale from the dipolar length  $(L_{\Omega} \approx J/\Omega)$  to the anisotropy length  $(L_{\rm K} \approx \sqrt{J/K})^{29}$  Because the exchange interaction, magnetic anisotropy, and dipolar interaction per unit area in a stack of identical 2D magnetic sheets scale differently with the film thickness, <sup>29</sup> one can expect in Fe<sub>3</sub>GeTe<sub>2</sub> a cross-over from a stripe-domain phase in the thick limit in which the dipolar interaction dominates to a single-domain phase in the ultrathin limit, where the magnetic anisotropy dominates. To search for this cross-over behavior, we imaged the stripe domains of

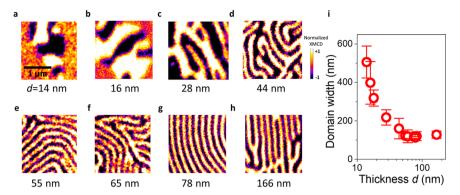


Figure 3. Thickness-dependent stripe domains at T = 110 K. Magnetic domain images from Fe<sub>3</sub>GeTe<sub>2</sub> flakes with thickness of (a) d = 14, (b) 16, (c) 28, (d) 44, (e) 55, (f) 65, (g) 78, and (h) 166 nm. The thickness was determined by AFM (Figure S1). (i) Stripe width as a function of Fe<sub>3</sub>GeTe<sub>2</sub> flake thickness.

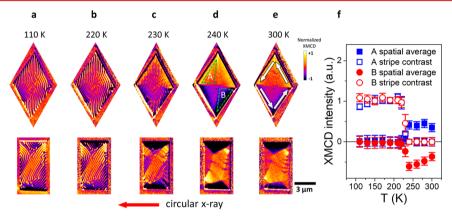


Figure 4. Magnetic domain images of patterned  $Fe_3GeTe_2$  microstructures. Micron-sized diamond-shaped and rectangular patterned structures in 250 nm  $Fe_3GeTe_2$  exhibit stripe domains between (a) T=110 K and (b) 220 K. The out-of-plane stripe contrast is weakened as the temperature approaches (c) 230 K and disappears at higher temperature, i.e., (d) 240 K and (e) 300 K. Meanwhile, an in-plane magnetic contrast develops above 230 K, showing the formation of a magnetic vortex state in the diamond-shaped microstructure and a multidomain state in the rectangular structure. (f) Temperature dependence of the magnetic stripe contrast (out-of-plane magnetization component) and the spatially averaged contrast (in-plane magnetization component) from the two selected areas (labeled as A and B in panel d) indicate a spin-reorientation transition from an out-of-plane stripe-domain phase at T < 230 K to an in-plane vortex phase at T > 230 K, with an enhanced  $T_C$  higher than room temperature. The arrows in panel e show the in-plane magnetization directions.

Fe<sub>3</sub>GeTe<sub>2</sub> flakes of different thicknesses at  $T=110~\rm K$  (Figure 3a–h). The stripe width indeed increases with decreasing Fe<sub>3</sub>GeTe<sub>2</sub> flake thickness (Figure 3i). Although no single-domain flakes were observed above 110 K, the rapid increase of domain width below ~20 nm in Figure 3i suggests the existence of a single-domain phase (stripe width greater than the sample size) in the ultrathin limit. In fact, the full magnetic remanence of Fe<sub>3</sub>GeTe<sub>2</sub> hysteresis loop below a critical thickness suggests indirectly the existence of this single-domain phase.<sup>30</sup>

Reducing the size and adjusting the shape of the  $Fe_3GeTe_2$  flakes are two effective mechanisms for tailoring magnetic dipolar interactions because the magnetic moments at the edges (also referred to as magnetic surface charge) produce a stray magnetic field (dipolar magnetic field) that increases the magneto-static energy of the system. Under certain conditions, minimizing the magnetic surface charge by aligning the magnetization vector to lie within the plane of the flake and parallel to the edges of the microstructure could be energetically beneficial in competing with the increased Heisenberg exchange interaction, leading to new magnetic-domain phases inside the microstructure. For example, a micron-sized disk above a critical thickness could form a

magnetic vortex state in which the magnetization vector circulates around the center of the disk.31 It was also discovered recently that patterned microstructures on coupled magnetic layers can lead to topological artificial skyrmions.<sup>3</sup> Encouraged by the result in Figure 3, which implicates the role of the dipolar interaction in the formation of the magneticstripe-domain phase of Fe<sub>3</sub>GeTe<sub>2</sub>, we utilized a focused ion beam (FIB) to pattern a Fe<sub>3</sub>GeTe<sub>2</sub> flake into a diamondshaped and a rectangular microstructure by sputtering away the Fe<sub>3</sub>GeTe<sub>2</sub> outside the microstructures. The sharp corners of the microstructures promote the reorientation of the in-plane magnetization vector to form either a magnetic vortex state or a multidomain state. The discussion below shows that the magnetization of patterned Fe<sub>3</sub>GeTe<sub>2</sub> microstructures undergoes a spin reorientation transition (SRT) from an out-ofplane stripe-domain phase at T < 230 K to an in-plane vortex (multidomain) phase at T > 230 K, with the  $T_C$  of the patterned Fe<sub>3</sub>GeTe<sub>2</sub> microstructures enhanced from the 230 K bulk value to above room temperature.

Figure 4 shows the magnetic domain images of the microstructures at different temperatures. At T=110 K, we observed the same stripe domains as in unpatterned  $Fe_3GeTe_2$  (Figure 4a). As the temperature approaches 230 K (Figure

4b,c), the stripe contrast becomes weaker than at T = 110 Kand even vanishes in some regions of the microstructures. However, unlike the unpatterned Fe<sub>3</sub>GeTe<sub>2</sub>, which has a zero spatially averaged XMCD, the spatially averaged XMCD signal in the microstructures is nonzero with different values in different regions of the microstructures (as seen by the different color background in different regions). Because the up and down stripes remain the same width at all temperatures, the spatially averaged nonzero XMCD corresponds to an inplane component of the magnetization, i.e., the magnetization vector of the magnetic stripes developed an in-plane component at temperature just below 230 K. At T = 240 K, which is above the bulk T<sub>C</sub> of unpatterned Fe<sub>3</sub>GeTe<sub>2</sub>, the outof-plane component of the stripes vanishes completely (Figure 4d). Surprisingly, instead of a paramagnetic state as seen in unpatterned Fe<sub>3</sub>GeTe<sub>2</sub> (Figure 2g,h), the in-plane component of the magnetization inside the microstructures remains and develops into a magnetic vortex state in the diamond-shaped microstructure and a magnetic multidomain state in the rectangular structure and persists up to the room temperature (Figure 4e). Our first measurement using a heated sample holder shows that the in-plane magnetic domain contrast vanishes roughly at ~370 K (Figure S2), indicating an enhancement of  $T_C$  from 230 K in bulk  $Fe_3GeTe_2$  to ~370 K in the Fe<sub>3</sub>GeTe<sub>2</sub> microstructure. Systematic studies on the size and shape dependence of  $T_{\rm C}$  will be the focus of future measurements. Interestingly, the stripe orientation has a tendency to be perpendicular to the microstructure boundary. This tendency can also be seen at the Fe<sub>3</sub>GeTe<sub>2</sub> flake boundary (Figure S1). Noting that low magneto-static energy corresponds to zero magnetic charge at the side surface (e.g., magnetization parallel to the boundary side surface), we speculate that the perpendicular alignment of the stripes to the edge may imply a parallel alignment of the in-plane domain wall magnetization to the boundary, i.e., the domain walls should be Néel-type rather than Bloch-type. Néel walls generally have a higher domain-wall energy than Bloch walls for stripe domains. However, a Dzyaloshinskii-Moriya interaction<sup>34</sup> could lower the energy of Néel walls, resulting in chiral Néel walls in magnetic thin films.<sup>35</sup> The inversion symmetry-breaking in Fe<sub>3</sub>GeTe<sub>2</sub> permits the existence of Dzyaloshinskii-Moriya interactions and thus could, in principle, lead to the formation of chiral Néel walls. However, the nature of the domain walls remains an open question due to the limitation of the spatial resolution of PEEM.

To ensure the integrity and veracity of these results, we have performed multiple experimental checks. First, we verified that the domain contrast in Figure 4d,e is from magnetic origin by confirming the contrast reversal using left- and right-circularly polarized X-rays. Second, we note that XMCD measures the projection of magnetization vector to the X-ray incidence direction so that out-of-plane magnetization should result in only two magnetic contrasts in PEEM images, such as in the stripe-domain phase. Then, the four different domain contrasts in Figure 4d,e can only come from the in-plane magnetization components. We confirm this by observing the domain contrast changes after rotating the sample by 90° around its surface normal direction (Figure S3). Third, we extracted the stripe contrast and the spatially averaged XMCD signals of the labeled areas (A and B in Figure 4d) as a function of temperature. We find that the disappearance of stripe contrast is accompanied by the rapid development of the averaged magnetic contrast at ~230 K, showing a SRT from out-ofplane to in-plane directions (Figure 4f). We point out that the in-plane XMCD signal (difference of blue and red solid symbols above 230 K in Figure 4f) has a similar magnitude as out-of-plane signal (open symbols below 230 K in Figure 4f), showing that the in-plane magnetization is a result of SRT rather than a residual in-plane magnetization. Last, we point out again that PEEM measurement probes only ~10 nm depth from the sample surface (the lattice constant is 1.63 nm along the c axis) so that we do not know if the whole Fe<sub>3</sub>GeTe<sub>2</sub> magnetization or only the top 10 nm magnetization switches to the in-plane direction in the microstructure. However, a vortex state should appear only above a critical thickness in a micro structure (~20-50 nm depending on the size and shape for micron-size microstructures).<sup>36</sup> Our micromagnetic simulations show that the vortex state should be stabilized in Fe<sub>3</sub>GeTe<sub>2</sub> microstructure only above 50 nm (Figure S4). The observation of the magnetic vortex state in the diamondshaped structure then indicates that the in-plane magnetization in our Fe<sub>3</sub>GeTe<sub>2</sub> microstructures should be at least thicker than the critical thickness (>50 nm) of the vortex formation. However, we still cannot rule out the possibility that a microstructure could consist of a near-surface region with an in-plane magnetization and a higher  $T_{\rm C}$  and a near-substrate region with an out-of-plane magnetization and  $T_C$  = 230 K so that the magnetic coupling between these two regions leads to an out-of-plane magnetized stripe domain phase at T < 230 Kand an in-plane vortex phase for the top part at T > 230 K. Resolution of this issue requires a magnetic microscopy measurement with a depth profile ability beyond the capability of our current experiments, such as scanning transmission Xray microscopy.

While we cannot provide a definite answer, we discuss here some possibilities as to the origin of the SRT and the enhancement of T<sub>C</sub> in the patterned Fe<sub>3</sub>GeTe<sub>2</sub> microstructures. The first possibility is a finite size effect. Diminishing the magnetic charges of stripe domain walls everywhere on the side surface is difficult without bending the magnetic stripes inside the microstructure. Either exposure of the magnetic charge at the side surface or a bending of the magnetic stripes could increase the magnetic energy of the system. Then, under certain conditions, a SRT from the out-ofplane stripe domain phase to an in-plane vortex state may possibly lower the total magnetic energy of the microstructure. However, micromagnetic calculations based on specific domain configurations and specific microstructure shapes show that an enhancement of the perpendicular magnetic anisotropy is expected with shrinking the size of a system,<sup>37</sup> which is the opposite of our result that a finite-size microstructure leads to preferential in-plane magnetization. In addition, a finite-size effect usually reduces  $T_{\rm C}$ , <sup>38,39</sup> which is also the opposite of our result. However, those works<sup>37–39</sup> were performed on conventional magnetic materials. Obviously, more theoretical studies are needed to explore the finite size effect for vdW magnetic materials (e.g., taking into account the structural and strain changes in finite-size vdW systems). A second possibility is the exposure of the microstructure's side surface to air before placing the sample into the PEEM vacuum chamber. The FIB process removes materials around the microstructure so that the edges of the microstructure could adsorb gas molecules after losing the Pd protection layer. However, we find that the stripe domains near the side boundary of Fe<sub>3</sub>GeTe<sub>2</sub> flakes (Figure S1), which are also exposed to air, are identical to the stripes in the interior area of the flakes and do not show a SRT

and an enhancement of  $T_C$ . Therefore, it is unlikely that the exposure of the edges to air is responsible for the SRT and the enhancement of  $T_C$  of the patterned microstructures. A third possibility is any chemical and structural changes of Fe<sub>3</sub>GeTe<sub>2</sub> due to FIB. FIB employs high-energy Ga<sup>+</sup> ions to sputter away materials in the desired area (e.g., the materials around the microstructure in our case), thus inevitably introducing small amount of Ga to the microstructures by Ga diffusion and ion implantation.<sup>40</sup> Although the amount of Ga is known to be tiny and is usually negligible for most of FIB studies, we do note that intentional Ga implantation can modify the magnetic anisotropy of metallic magnetic thin films. 41 Although our FIB process sputtered only area outside the microstructures and did not knowingly implant Ga to the microstructures, Ga distribution analysis confirm that most Ga atoms are at the microstructure edges rather than inside the microstructure (Figure S5). X-ray absorption microspectroscopy does not show noticeable changes of the Fe absorption spectra in the microstructure as compared with regions away from the Ga patterning, so there does not appear to be a substantial change of the Fe<sub>3</sub>GeTe<sub>2</sub> stoichiometry or electronic structure in the patterned microstructure compared with the unpatterned flakes. We do not know if the Ga at the edges of the microstructure could diffuse or be implanted into the microstructure by a miniscule amount that is undetectable in the Fe XAS but somehow sufficient to change the magnetic properties of the Fe<sub>3</sub>GeTe<sub>2</sub>. It should be mentioned that the XMCD signal above 230 K for in-plane magnetization has a similar magnitude as out-of-plane magnetization below 230 K. Thus, we can rule out the influence of Ga defect-localized inplane magnetization, such as that found in defected graphene,  $^{42}$  given the upper limit of Ga fluence of 5  $\times$  10<sup>-2</sup>/  $Å^2$  (Figure S5). Nevertheless we cannot definitively rule out the influence of Ga, especially when taking into account the sensitive dependence of Fe<sub>3</sub>GeTe<sub>2</sub> magnetic properties on chemical environment. 11 Obviously, more investigations are needed on the effect of Ga and any foreign atoms on Fe<sub>3</sub>GeTe<sub>2</sub>. Therefore, the effects of Ga on the SRT and the  $T_C$ enhancement of the Fe<sub>3</sub>GeTe<sub>2</sub> patterned structures remain an open question and need future investigation.

In summary, we demonstrate tunable ferromagnetic characteristics of Fe<sub>3</sub>GeTe<sub>2</sub> vdW materials even beyond room temperature. Bulk Fe<sub>3</sub>GeTe<sub>2</sub> has a magnetic long-range ordered stripe-domain phase below the Curie temperature of  $T_{\rm C} \approx 230$  K. The stripe-domain phase is identified as alternating up and down magnetic domains, with the stripe width increasing rapidly with decreasing sample thickness. By patterning Fe<sub>3</sub>GeTe<sub>2</sub> into micron-sized microstructures using focused ion beam, we are able to change the magnetic domain phase from out-of-plane stripe domain phase below 230 K to in-plane vortex (multidomain) phase that exists above 230 K and as high as 370 K, making it stable at room temperature. These results open up exciting opportunities for the use of room temperature vdW magnets in such applications as lowpower spintronics, high-density magnetic storage, and flexible electronics.

#### ASSOCIATED CONTENT

#### S Supporting Information

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acs.nanolett.8b02806.

Additional experimental details including sample fabrication, XMCD and PEEM measurement,  $Fe_3GeTe_2$  flake magnetic-stripe domains and atomic force microscopy characterizations, Curie temperature determination of a rectangular microstructure, in-plane magnetic vortex state before and after  $90^{\circ}$  in-plane rotation, micromagnetic simulation results of different domain configurations for microstructure, and  $Ga^+$  distribution in patterned microstructures (PDF)

#### AUTHOR INFORMATION

#### **Corresponding Authors**

\*E-mail: jiali83@pku.edu.cn. Phone: (010)-62760115. \*E-mail: qiu@berkeley.edu. Phone: (510) 643-8843. Fax: (510) 643-8497.

#### ORCID ®

Padraic Shafer: 0000-0001-9363-2557 Kai Liu: 0000-0001-9413-6782

Chanyong Hwang: 0000-0002-6612-7552 Xiang Zhang: 0000-0002-3272-894X Ziqiang Qiu: 0000-0003-0680-0714

#### **Author Contributions**

Q.L., M.Y., C.G., J.L., and Z.Q.Q designed and performed experiments, analyzed data, and wrote the paper. R.V.C., A.T.N., G.C., A.S., P.S., and E.A. performed the X-ray measurements and discussion. J.T. helped with the FIB fabrication. S.W. and F.W. helped with the AFM characterization. A.S.A. and S.-W.C. provided bulk crystals. A.K.S., K.L., N.G., C.H., and X.Z. were involved in the data analysis and discussion. Q.L. and M.Y. contributed equally.

#### Note

The authors declare no competing financial interest.

# ACKNOWLEDGMENTS

This work is supported by the U.S. Department of Energy, Office of Science, Office of Basic Energy Sciences, Materials Sciences and Engineering Division under contract no. DE-AC02-05-CH11231 (van der Waals heterostructures program, KCWF16), the National Science Foundation grant nos. DMR-1504568 and DMR-1610060, the UC Office of the President Multicampus Research Programs and Initiatives MRP-17-454963, the Future Materials Discovery Program through the National Research Foundation of Korea (no. 2015M3D1A1070467), and the Science Research Center Program through the National Research Foundation of Korea (no. 2015R1A5A1009962). This research used resources of the Advanced Light Source, which is a DOE Office of Science User Facility under contract no. DE-AC02-05CH11231. Work at the Molecular Foundry was supported by the Office of Science, Office of Basic Energy Sciences, of the U.S. Department of Energy under contract no. DE-AC02-05CH11231. The work at Rutgers was funded by the Gordon and Betty Moore Foundation's EPiQS Initiative through grant no. GBMF4413 to the Rutgers Center for Emergent Materials.

#### REFERENCES

- (1) Gong, C.; Li, L.; Li, Z.; Ji, H.; Stern, A.; Xia, Y.; Cao, T.; Bao, W.; Wang, C.; Wang, Y.; Qiu, Z. Q.; Cava, R. J.; Louie, S. G.; Xia, J.; Zhang, X. *Nature* **2017**, *546*, 265–269.
- (2) Huang, B.; Clark, G.; Navarro-Moratalla, E.; Klein, D. R.; Cheng, R.; Seyler, K. L.; Zhong, D.; Schmidgall, E.; McGuire, M. A.; Cobden,

D. H.; Yao, W.; Xiao, D.; Jarillo-Herrero, P.; Xu, X. Nature 2017, 546, 270-273.

- (3) Bonilla, M.; Kolekar, S.; Ma, Y.; Diaz, H. C.; Kalappattil, V.; Das, R.; Eggers, T.; Gutierrez, H. R.; Phan, M.-H.; Batzill, M. Nat. Nanotechnol. 2018, 13, 289–293.
- (4) O'Hara, D. J.; Zhu, T.; Trout, A. H.; Ahmed, A. S.; Luo, Y. K.; Lee, C. H.; Brenner, M. R.; Rajan, S.; Gupta, J. A.; McComb, D. W.; Kawakami, R. K. *Nano Lett.* **2018**, *18*, 3125–3131.
- (5) Deiseroth, H.-J.; Aleksandrov, K.; Reiner, C.; Kienle, L.; Kremer, R. K. Eur. J. Inorg. Chem. **2006**, 2006, 1561–1567.
- (6) Chen, B.; Yang, J. H.; Wang, H. D.; Imai, M.; Ohta, H.; Michioka, C.; Yoshimura, K.; Fang, M. H. J. Phys. Soc. Jpn. 2013, 82, 124711.
- (7) Zhu, J.-X.; Janoschek, M.; Chaves, D. S.; Cezar, J. C.; Durakiewicz, T.; Ronning, F.; Sassa, Y.; Mansson, M.; Scott, B. L.; Wakeham, N.; Bauer, E. D.; Thompson, J. D. *Phys. Rev. B: Condens. Matter Mater. Phys.* **2016**, 93, 144404.
- (8) Liu, B.; Zou, Y.; Zhou, S.; Zhang, L.; Wang, Z.; Li, H.; Qu, Z.; Zhang, Y. Sci. Rep. 2017, 7, 6184.
- (9) May, A. F.; Calder, S.; Cantoni, C.; Cao, H.; McGuire, M. A. Phys. Rev. B: Condens. Matter Mater. Phys. 2016, 93, 014411.
- (10) Liu, Y.; Ivanovski, V. N.; Petrovic, C. Phys. Rev. B: Condens. Matter Mater. Phys. 2017, 96, 144429.
- (11) Zhuang, H. L.; Kent, P. R. C.; Hennig, R. G. Phys. Rev. B: Condens. Matter Mater. Phys. 2016, 93, 134407.
- (12) Leon-Brito, N.; Bauer, E. D.; Ronning, F.; Thompson, J. D.; Moyshovich, R. *J. Appl. Phys.* **2016**, *120*, 083903.
- (13) Yi, J.; Zhuang, H.; Zou, Q.; Wu, Z.; Cao, G.; Tang, S.; Calder, S. A.; Kent, P. R. C.; Mandrus, D.; Gai, Z. 2D Mater. 2017, 4, 011005.
- (14) Nguyen, G. D.; Lee, J.; Berlijn, T.; Zou, Q.; Hus, S. M.; Park, J.; Gai, Z.; Lee, C.; Li, A.-P. *Phys. Rev. B: Condens. Matter Mater. Phys.* **2018**, 97, 014425.
- (15) Wang, Y.; Xian, C.; Wang, J.; Liu, B.; Ling, L.; Zhang, L.; Cao, L.; Qu, Z.; Xiong, Y. Phys. Rev. B: Condens. Matter Mater. Phys. 2017, 96, 134428.
- (16) Liu, S.; Yuan, X.; Zou, Y.; Sheng, Y.; Huang, C.; Zhang, E.; Ling, J.; Liu, Y.; Wang, W.; Zhang, C.; Zou, J.; Wang, K.; Xiu, F. npj 2D Mater. Appl. 2017, 1, 30.
- (17) Zhang, Y.; Lu, H.; Zhu, X.; Tan, S.; Feng, W.; Liu, Q.; Zhang, W.; Chen, Q.; Liu, Y.; Luo, X.; Xie, D.; Luo, L.; Zhang, Z.; Lai, X. Sci. Adv. 2018, 4, eaao6791.
- (18) Mermin, N. D.; Wagner, H. Phys. Rev. Lett. 1966, 17, 1133.
- (19) Bander, M.; Mills, D. L. Phys. Rev. B: Condens. Matter Mater. Phys. 1988, 38, 12015.
- (20) Nakajima, R.; Stöhr, J.; Idzerda, Y. U. Phys. Rev. B: Condens. Matter Mater. Phys. 1999, 59, 6421.
- (21) Kittel, C. Rev. Mod. Phys. 1949, 21, 541.
- (22) Allenspach, R.; Bischof, A. Phys. Rev. Lett. 1992, 69, 3385.
- (23) Portmann, O.; Vaterlaus, A.; Pescia, D. *Nature* **2003**, 422, 701–704.
- (24) Wu, Y. Z.; Won, C.; Scholl, A.; Doran, A.; Zhao, H. W.; Jin, X. F.; Qiu, Z. Q. Phys. Rev. Lett. **2004**, 93, 117205.
- (25) Davies, J. E.; Hellwig, O.; Fullerton, E. E.; Denbeaux, G.; Kortright, J. B.; Liu, K. Phys. Rev. B: Condens. Matter Mater. Phys. 2004, 70, 224434.
- (26) Westover, A. S.; Chesnel, K.; Hatch, K.; Salter, P.; Hellwig, O. J. Magn. Magn. Mater. **2016**, 399, 164–169.
- (27) Kashuba, A.; Pokrovsky, V. L. Phys. Rev. Lett. 1993, 70, 3155.
- (28) Yafet, Y.; Gyorgy, E. M. Phys. Rev. B: Condens. Matter Mater. Phys. 1988, 38, 9145.
- (29) Won, C.; Wu, Y. Z.; Choi, J.; Kim, W.; Scholl, A.; Doran, A.; Owens, T.; Wu, J.; Jin, X. F.; Zhao, H. W.; Qiu, Z. Q. *Phys. Rev. B: Condens. Matter Mater. Phys.* **2005**, *71*, 224429.
- (30) Tan, C.; Lee, J.; Jung, S.-G.; Park, T.; Albarakati, S.; Partridge, J.; Field, M. R.; McCulloch, D. G.; Wang, L.; Lee, C. Nat. Commun. 2018, 9, 1554.
- (31) Shinjo, T.; Okuno, T.; Hassdorf, R.; Shigeto, K.; Ono, T. Science 2000, 289, 930-932.

(32) Li, J.; Tan, A.; Moon, K. W.; Doran, A.; Marcus, M. A.; Young, A. T.; Arenholz, E.; Ma, S.; Yang, R. F.; Hwang, C.; Qiu, Z. Q. *Nat. Commun.* **2014**, *5*, 4704.

- (33) Gilbert, D. A.; Maranville, B. B.; Balk, A. L.; Kirby, B. J.; Fischer, P.; Pierce, D. T.; Unguris, J.; Borchers, J. A.; Liu, K. Nat. Commun. 2015, 6, 8462.
- (34) Dzyaloshinskii, I. E. Sov. Phys. JETP 1964, 19, 960-971.
- (35) Chen, G.; Zhu, J.; Quesada, A.; Li, J.; N'Diaye, A. T.; Huo, Y.; Ma, T. P.; Chen, Y.; Kwon, H. Y.; Won, C.; Qiu, Z. Q.; Schmid, A. K.; Wu, Y. Z. *Phys. Rev. Lett.* **2013**, *110*, 177204.
- (36) Cimpoesu, D.; Stoleriu, L.; Stancu, A. J. Appl. Phys. 2013, 114, 223901.
- (37) Vedmedenko, E. Y.; Oepen, H. P.; Kirschner, J. Phys. Rev. B: Condens. Matter Mater. Phys. 2003, 67, 012409.
- (38) Iglesias, O.; Labarta, A. Phys. Rev. B: Condens. Matter Mater. Phys. 2001, 63, 184416.
- (39) Sun, L.; Searson, P. C.; Chien, C. L. Phys. Rev. B: Condens. Matter Mater. Phys. 2000, 61, 6463.
- (40) Miller, M. K.; Russell, K. F.; Thompson, K.; Alvis, R.; Larson, D. J. Microsc. Microanal. **2007**, *13*, 428–436.
- (41) Hyndman, R.; Warin, P.; Gierak, J.; Ferré, J.; Chapman, J. N.; Jamet, J. P.; Mathet, V.; Chappert, C. J. Appl. Phys. 2001, 90, 3843.
- (42) Nair, R. R.; Tsai, I.-L.; Sepioni, M.; Lehtinen, O.; Keinonen, J.; Krasheninnikov, A. V.; Castro Neto, A. H.; Katsnelson, M. I.; Geim, A. K.; Grigorieva, I. V. *Nat. Commun.* **2013**, *4*, 2010.